4-20mA OUTPUT MICROPROCESSOR CORRECTED IS® PRESSURE TRANSMITTER BME-76I-1100 SERIES

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- Robust ConstructionHigh Accuracy
- High AccuracyMicroprocesso
- Microprocessor Corrected
 Silicon on Silicon Integrated Sensor VIS[®]

The BME-76I-1100 microprocessor corrected transmitter offers high accuracy with a total error band of $\pm 0.25\%$ FSO, inclusive of all errors over a wide temperature range of -40° F to $+250^{\circ}$ F. The ingenious application of modern solid state technology to transducer sensing makes the BME-76I-1100 Series the most advanced pressure transducer available. Designed to measure liquid or gas pressure, the transducer

is of all-welded stainless steel construction, with integral pressure port and diaphragm.



CHART FOR "X" -1 X=Ø.031 -2 X=Ø.172 PIN DESIGNATION A + INPUT B - INPUT C SPARE D FACTORY USE ONLY E CASE F FACTORY USE ONLY	"X" PRESSURE 2.70 (68.5) INLET ORIFICE 35 (14) 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0
INPUT Pressure Range	1.7 3.5 7 17 35 70 140 350 BAR 25 50 100 250 500 1000 2000 5000 PSI
Operational Mode	Absolute, Sealed Gage
Over Pressure	2 Times Rated Pressure to a Maximum of 5000 PSI (350 BAR)
Burst Pressure	5 Times Rated Pressure to a Maximum of 5000 PSI (350 BAR)
Pressure Media	Any Media Compatible With 316 SS and 15-5 PH Stainless Steel
Rated Electrical Excitation	8 - 32 VDC
OUTPUT Output	4 mA - 20 mA Current Output
Total Error Band (Excluding End Points)	± 0.25% FSO (Max.) (Combined Non-Linearity, Hysteresis, Repeatability and All Thermal Effects Included)
Residual Unbalance	1.0 VDC \pm 0.025 (4 mA \pm 0.1 Shunted by a 250 Ω Resistor)
Sensitivity	4.0 VDC \pm 0.025 (16 mA \pm 0.1 Shunted by a 250 Ω Resistor)
Bandwidth (-3dB)	DC to 1 kHz
Resolution	Infinitesimal
Acceleration Sensitivity % FS/g Perpendicular Transverse	$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$
Insulation Resistance	100 Megohm Min. @ 50 VDC
ENVIRONMENTAL Operating Temperature Range	-40°F to +265°F (-40°C to +130°C)
Compensated Temperature Range	-40°F to +250°F (-40°C to +120°C)
Linear Vibration	50g Peak, Sine 10 to 2000 Hz
Altitude	-150 ft. to +70,000 ft. Will Not Damage Sensor
Humidity	100% Relative Humidity
Mechanical Shock	100g half Sine Wave 11 msec. Duration
PHYSICAL Electrical Connection	PTIH-10-6P Connector or Equivalent
Weight	110 Grams
Pressure Sensing Principle	Fully Active Four Arm Wheatstone Bridge Dielectrically Isolated Silicon on Silicon
Mounting Torque	100 Inch-Pounds (Max.)

Continuous development and refinement of our products may result in specification changes without notice - all dimensions nominal. (J)

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